Phototransistor, top view type RPT-34PB3F

The RPT-34PB3F is a silicon planar phototransistor.

It is particularly suited for use with a ROHM SIR-34ST3F infrared light emitting diode.

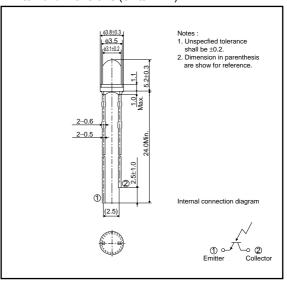
Applications

Optical control equipment

● Features

High sensitivity.

●External dimensions (Units : mm)



● Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol Limits		Unit
Collector-emitter voltage	Vceo	32	V
Emitter-collector voltage	Veco	5	V
Collector current	Ic	30	mA
Collector power dissipation	Pc	150	mW
Operating temperature	Topr	-25~+85	°C
Storage temperature	Tstg	-30~+100	°C

●Electrical and optical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Light current	Ic	2.0	-	-	mA	Vce=5V, E=500Lx
Dark current	ICEO	-	-	0.5	μΑ	Vce=10V(Black box)
Peak sensitivity wavelength	λР	_	800	-	nm	_
Collector-emitter saturation voltage	VCE(sat)	-	-	0.4	V	Ic=1mA, E=500Lx
Half-angle	θ1/2	_	±36	_	deg	-
Response time	tr-tf	-	10	-	μs	Vcc=5V, Ic=1mA, RL=100Ω

ROHM

•Electrical and optical characteristic curves

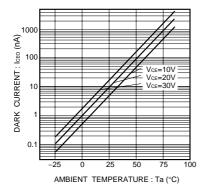


Fig.1 Dark current vs. ambient temperature

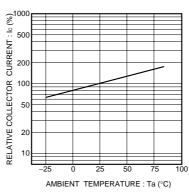


Fig.2 Relative output vs. ambient temperature

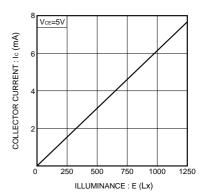


Fig.3 Light current vs. irradiance

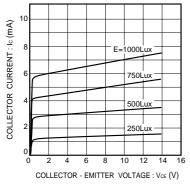


Fig.4 Output characteristics

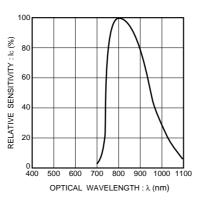


Fig.5 Spectral sensitivity

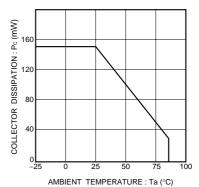


Fig.6 Collector dissipation vs. ambient temperature

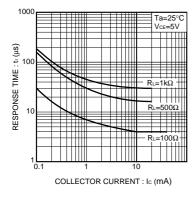
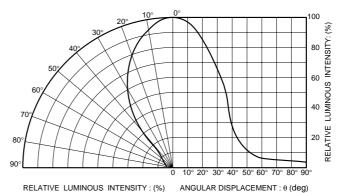


Fig.7 Response time vs. collector current



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Fig.8 Directional pattern

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